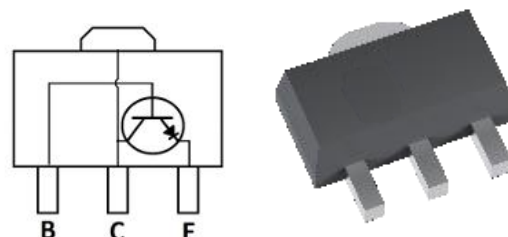


SOT-89 Bipolar Transistor 双极型三极管

■ **Features 特点**

NPN High Voltage 高压

■ **Absolute Maximum Ratings 最大额定值**



Characteristic 特性参数	Symbol 符号	Rat 额定值	Unit 单位
Collector-Base Voltage 集电极基极电压	V_{CBO}	400	V
Collector-Emitter Voltage 集电极发射极电压	V_{CEO}	400	V
Emitter-Base Voltage 发射极基极电压	V_{EBO}	5	V
Collector Current 集电极电流	I_C	200	mA
Collector Current Pulsed 集电极脉冲电流	I_{CP}	300	mA
Power dissipation 耗散功率	$P_C(T_a=25^{\circ}C)$	500	mW
Thermal Resistance Junction-Ambient 热阻	$R_{\theta JA}$	250	$^{\circ}C/W$
Junction and Storage Temperature 结温和储藏温度	T_J, T_{stg}	-55to+150 $^{\circ}C$	

■ **Device Marking 产品打标**

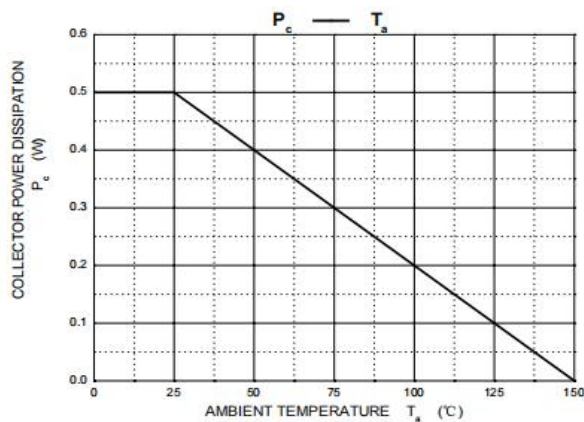
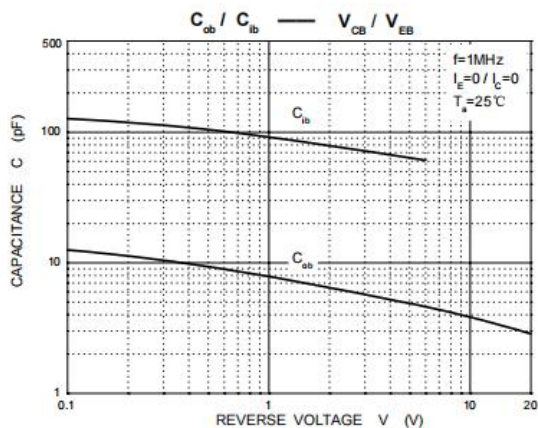
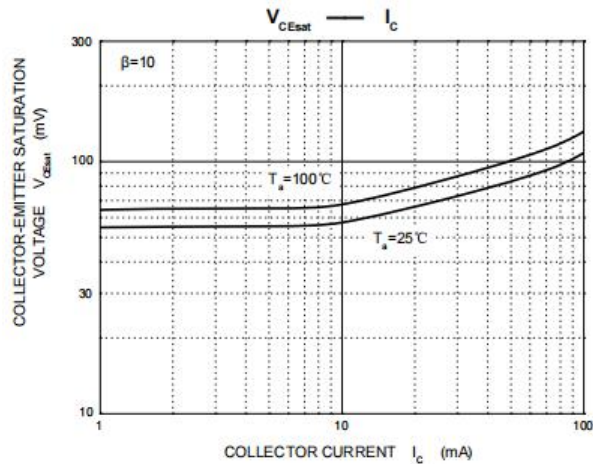
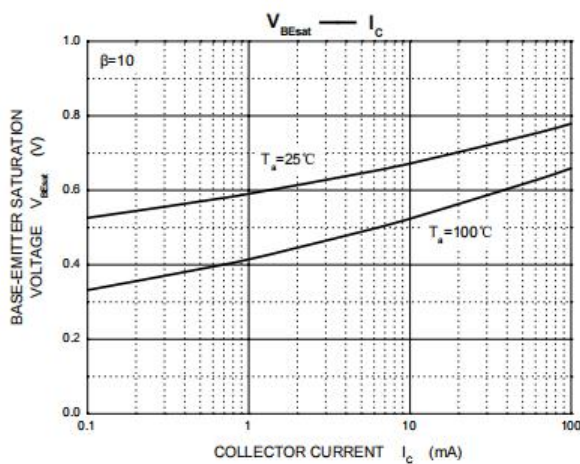
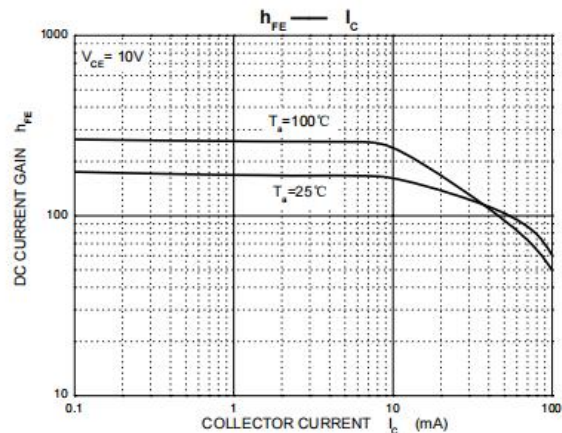
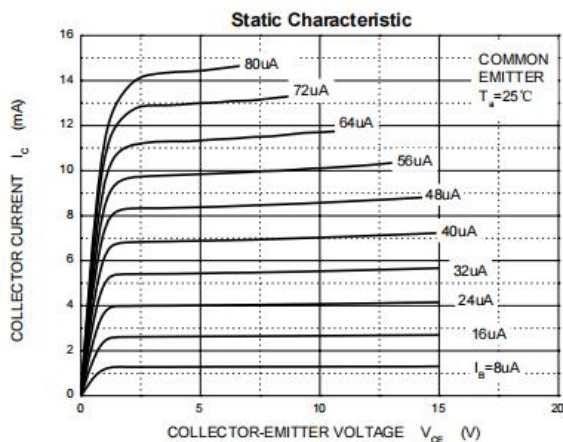
A44=A44

■Electrical Characteristics 电特性

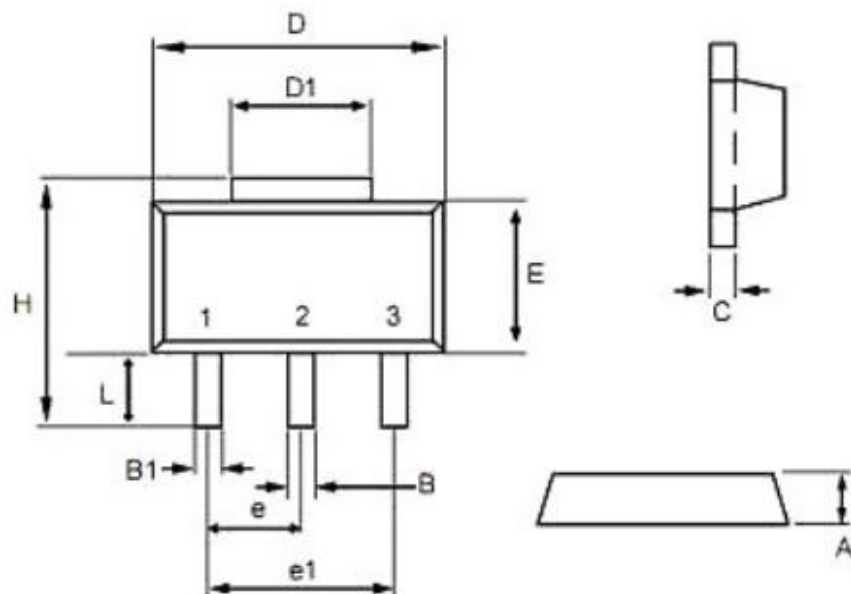
(TA=25℃ unless otherwise noted 如无特殊说明, 温度为 25℃)

Characteristic 特性参数	Symbol 符号	Min 最小值	Type 典型值	Max 最大值	Unit 单位
Collector-Base Breakdown Voltage 集电极基极击穿电压(IC= 100μA, IE=0)	BV _{CBO}	400	—	—	V
Collector-Emitter Breakdown Voltage 集电极发射极击穿电压(IC= 1mA, IB=0)	BV _{CEO}	400	—	—	V
Emitter-Base Breakdown Voltage 发射极基极击穿电压(IE= 100μA, IC=0)	BV _{EBO}	5	—	—	V
Collector-Base Leakage Current 集电极基极漏电流(V _{CB} = 400V, IE=0)	I _{CBO}	—	—	100	nA
Collector-Emitter Leakage Current 集电极发射极漏电流(V _{CE} = 400V, IB=0)	I _{CEO}	—	—	5	μA
Emitter-Base Leakage Current 发射极基极漏电流(V _{EB} = 5V, IC=0)	I _{EBO}	—	—	100	nA
DC Current Gain 直流电流增益(V _{CE} = 10V, IC= 1mA)	H _{FE} (1)	70	—	—	
DC Current Gain 直流电流增益(V _{CE} = 10V, IC= 10mA)	H _{FE} (2)	100	—	200	
DC Current Gain 直流电流增益(V _{CE} = 10V, IC= 50mA)	H _{FE} (3)	40	—	—	
DC Current Gain 直流电流增益(V _{CE} = 10V, IC= 100mA)	H _{FE} (4)	40	—	—	
Collector-Emitter Saturation Voltage 集电极发射极饱和压降(IC= 10mA, IB= 1mA) (IC= 50mA, IB= 5mA)	V _{CE(sat)}	—	—	0.2 0.3	V
Base-Emitter Saturation Voltage 基极发射极饱和压降(IC= 10mA, IB= 1mA)	V _{BE(sat)}	—	—	0.75	V
Transition Frequency 特征频率(V _{CE} = 20V, IC= 10mA)	f _T	50	—	—	MHz
Output Capacitance 输出电容(V _{CB} = 20V, IE=0, f=1MHz)	C _{ob}	—	6	—	pF

■ Typical Characteristic Curve 典型特性曲线



■Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.40	1.60	0.055	0.063
B	0.40	0.56	0.016	0.022
B1	0.35	0.48	0.014	0.019
C	0.35	0.44	0.014	0.017
D	4.40	4.60	0.173	0.181
D1	1.35	1.83	0.053	0.072
e	1.45	1.55	0.057	0.061
e1	2.95	3.05	0.116	0.120
E	2.29	2.60	0.090	0.102
H	3.75	4.25	0.148	0.167
L	0.80	1.20	0.031	0.047